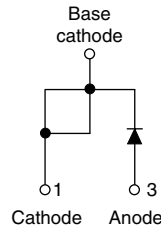


## High Performance Schottky Generation 5.0, 10 A


**TO-220AC**

**FEATURES**

- 175 °C high performance Schottky diode
- Very low forward voltage drop
- Extremely low reverse leakage
- Optimized  $V_F$  vs.  $I_F$  trade off for high efficiency
- Increased ruggedness for reverse avalanche capability
- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Full lead (Pb)-free and RoHS compliant devices
- Designed and qualified for industrial level


**RoHS  
COMPLIANT**
**PRODUCT SUMMARY**

$I_{F(AV)}$	10 A
$V_R$	100 V
$V_F$ at 10 A at 125 °C	0.68 V

**APPLICATIONS**

- High efficiency SMPS
- Automotive
- High frequency switching
- Output rectification
- Reverse battery protection
- Freewheeling
- Dc-to-dc systems
- Increased power density systems

**MAJOR RATINGS AND CHARACTERISTICS**

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$V_{RRM}$		100	V
$V_F$	10 Apk, $T_J = 125$ °C (typical)	0.62	
$T_J$	Range	- 55 to 175	°C

**VOLTAGE RATINGS**

PARAMETER	SYMBOL	TEST CONDITIONS	MBR10T100	UNITS
Maximum DC reverse voltage	$V_R$	$T_J = 25$ °C	100	V

**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	50 % duty cycle at $T_C = 159$ °C, rectangular waveform	10	A
Maximum peak one cycle non-repetitive surge current	$I_{FSM}$	5 $\mu$ s sine or 3 $\mu$ s rect. pulse	Following any rated load condition and with rated $V_{RRM}$ applied	850
		10 ms sine or 6 ms rect. pulse		200
Non-repetitive avalanche energy	$E_{AS}$	$T_J = 25$ °C, $I_{AS} = 3$ A, $L = 12$ mH	54	mJ
Repetitive avalanche current	$I_{AR}$	Limited by frequency of operation and time pulse duration so that $T_J < T_{J \text{ max}}$ . $I_{AS}$ at $T_J \text{ max}$ . as a function of time pulse See fig. 8	$I_{AS}$ at $T_J \text{ max}$ .	A



ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop per leg	$V_{FM}^{(1)}$	10 A	$T_J = 25\text{ }^\circ\text{C}$	-	0.79	V
		20 A		-	0.88	
		10 A	$T_J = 125\text{ }^\circ\text{C}$	-	0.68	
		20 A		-	0.8	
Reverse leakage current per leg	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	-	100	$\mu\text{A}$
		$T_J = 125\text{ }^\circ\text{C}$		-	4	mA
Junction capacitance per leg	$C_T$	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) $25\text{ }^\circ\text{C}$		400	-	pF
Series inductance per leg	$L_S$	Measured lead to lead 5 mm from package body		8.0	-	nH
Maximum voltage rate of change	dV/dt	Rated $V_R$		-	10 000	V/ $\mu\text{s}$

**Note**

(1) Pulse width < 300  $\mu\text{s}$ , duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		- 55 to 175	$^\circ\text{C}$
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation	2	$^\circ\text{C/W}$
Typical thermal resistance, case to heatsink	$R_{thCS}$	Mounting surface, smooth and greased	0.5	
Approximate weight			2	g
			0.07	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style TO-220AC	MBR10T100	

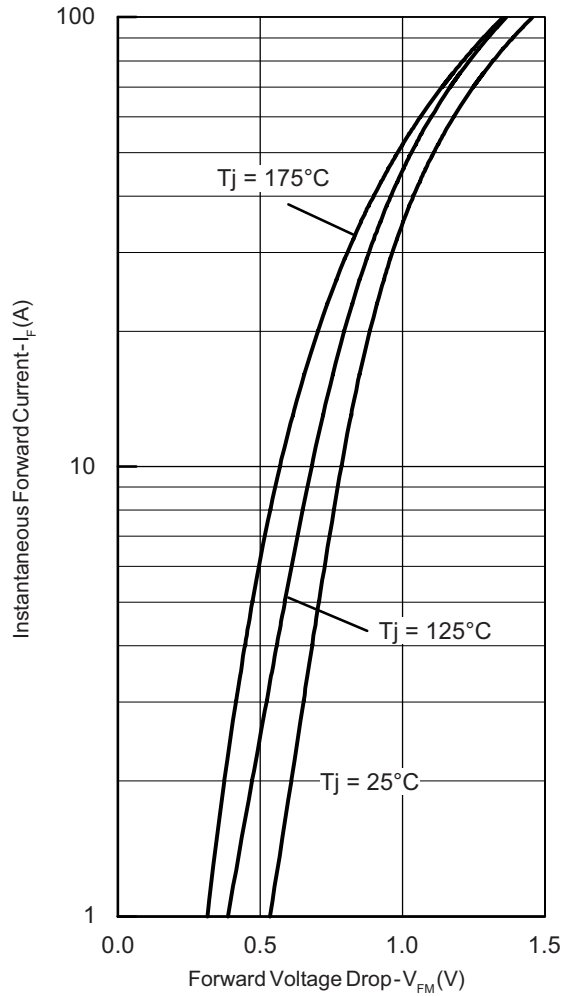


Fig. 1 - Maximum Forward Voltage Drop Characteristics

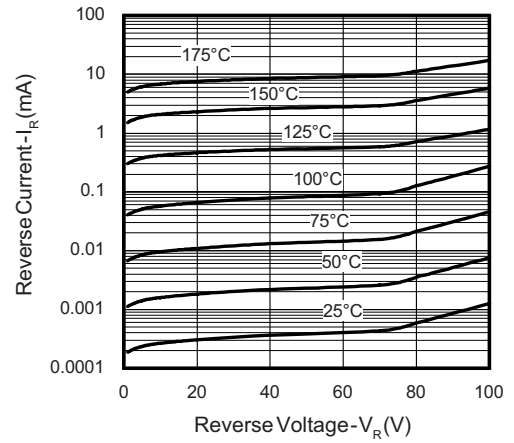


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

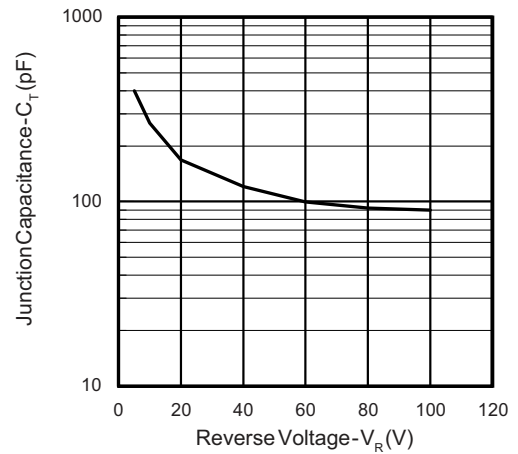
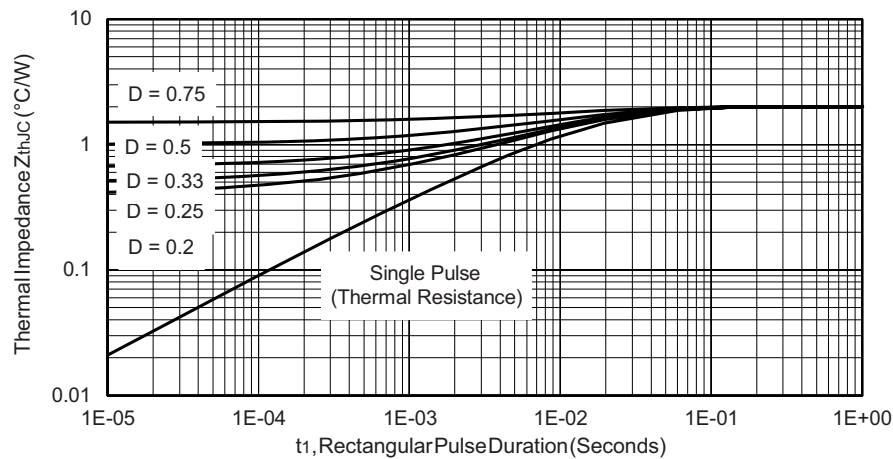


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage


 Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

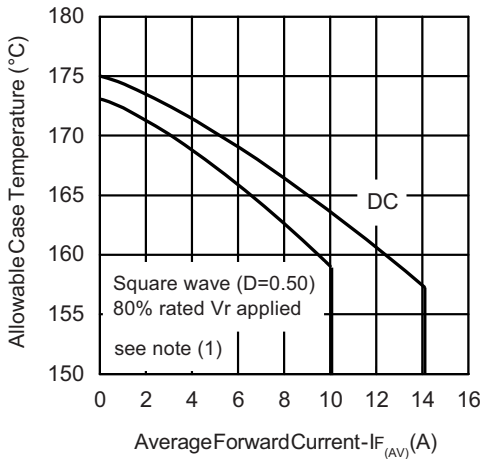


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

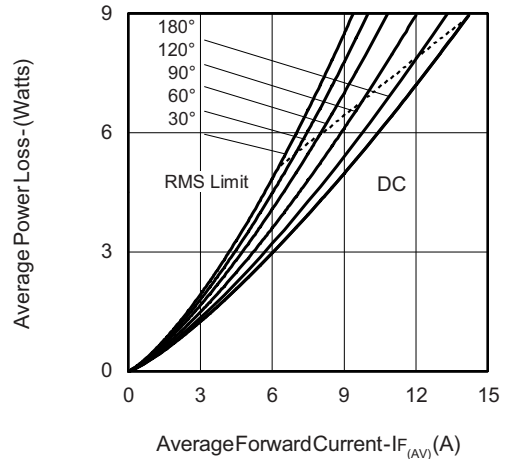


Fig. 6 - Forward Power Loss Characteristics

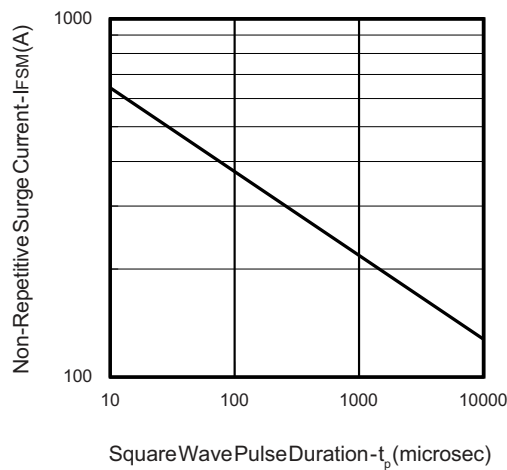


Fig. 7 - Maximum Non-Repetitive Surge Current

**Note**

- (1) Formula used:  $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$ ;  
 $P_d = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D)$  (see fig. 6);  
 $P_{d_{REV}} = \text{Inverse power loss} = V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80\%$  rated  $V_R$

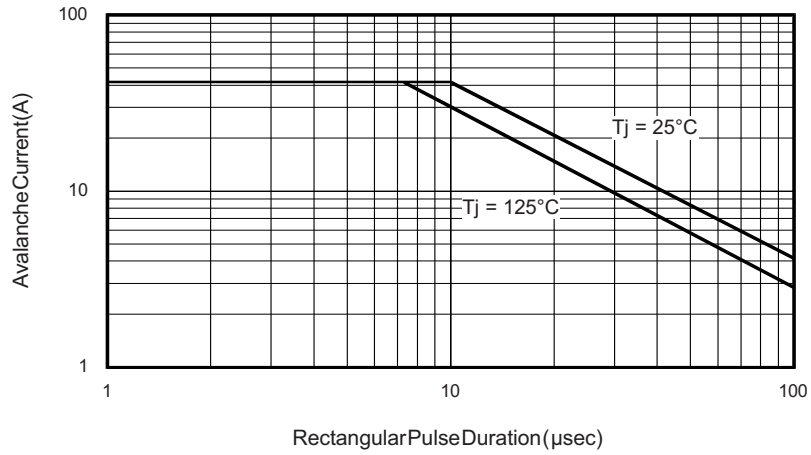


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

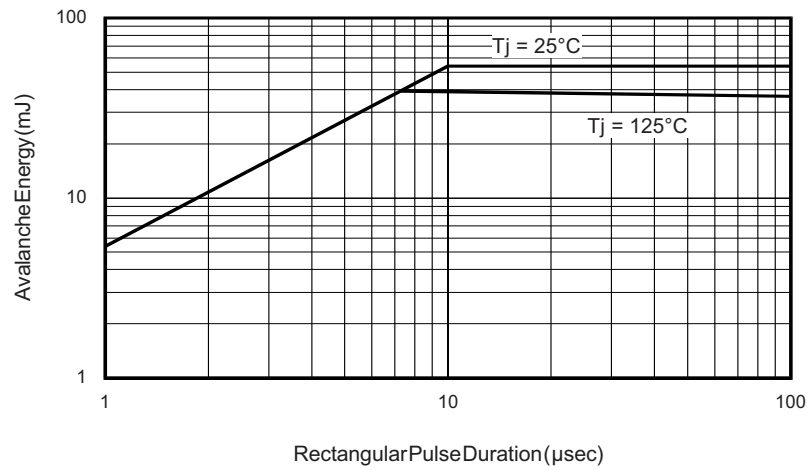


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)

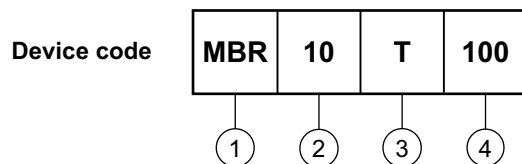
# MBR10T100

Vishay High Power Products

High Performance  
Schottky Generation 5.0, 10 A



## ORDERING INFORMATION TABLE



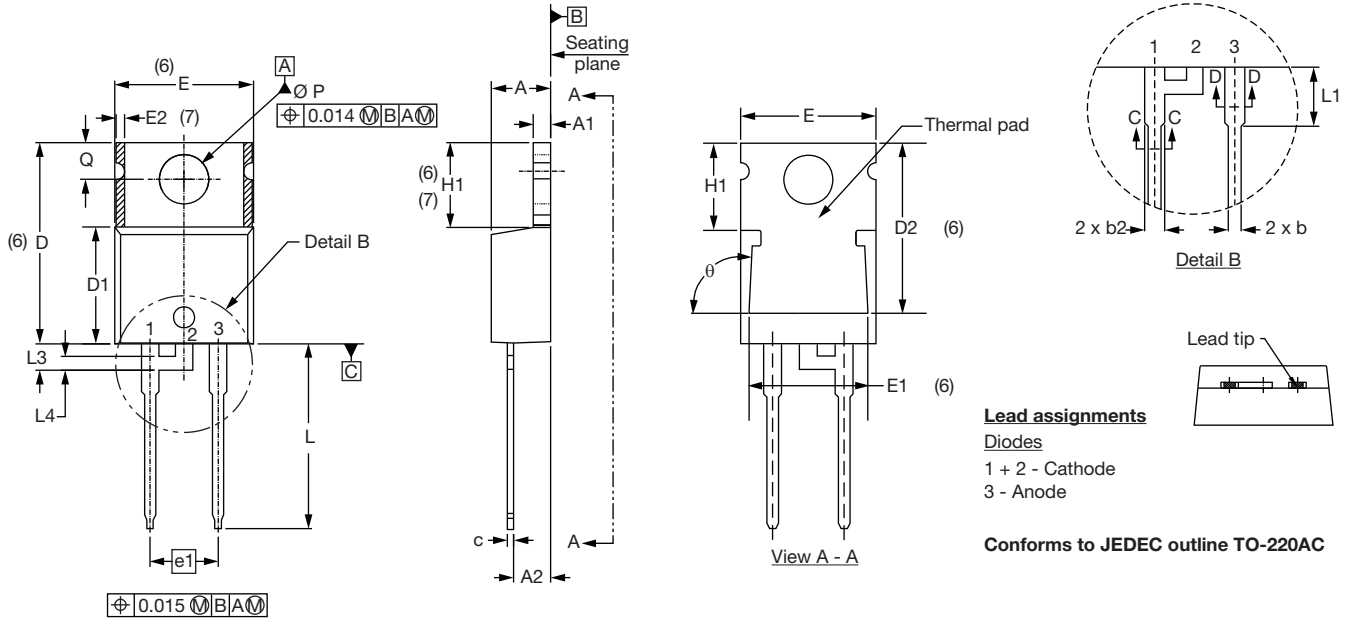
- 1** - MBR series
- 2** - Current rating (10 = 10 A)
- 3** - T = Trench
- 4** - Voltage rating (100 = 100 V)

Tube standard pack quantity: 50 pieces

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95221">http://www.vishay.com/doc?95221</a>
Part marking information	<a href="http://www.vishay.com/doc?95224">http://www.vishay.com/doc?95224</a>

## TO-220AC

**DIMENSIONS** in millimeters and inches



**Lead assignments**

Diodes  
 1 + 2 - Cathode  
 3 - Anode

Conforms to JEDEC outline TO-220AC

SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	4.25	4.65	0.167	0.183		E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055		E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115		e	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040		e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4	H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068		L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4	L1	3.32	3.82	0.131	0.150	2
c	0.36	0.61	0.014	0.024		L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4	L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3	$\varnothing P$	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6	$\theta$	90° to 93°		90° to 93°		
E	10.11	10.51	0.398	0.414	3, 6						

**Notes**

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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